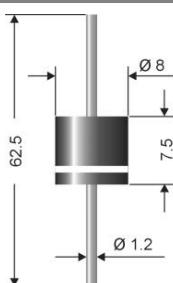


# HE 12FA ... HE 12FG



Axial lead diode

Type	Repetitive peak reverse voltage $V_{RRM}$ V	Surge peak reverse voltage $V_{RSM}$ V	Max. reverse recovery time $I_F = 0,5\text{ A}$ $I_R = 1\text{ A}$ $I_{RR} = 0,25\text{ A}$ $t_{rr}$ ns	Max. forward voltage $V_F^2)$
HE 12FA	50	50	200	0,82
HE 12FB	100	100	200	0,82
HE 12FD	200	200	200	0,82
HE 12FG	400	400	200	0,82

High efficiency fast silicon rectifier diode

HE 12FA...HE 12FG

Forward Current: 12 A

Reverse Voltage: 50 to 400 V

## Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

## Mechanical Data

- Plastic case 8 x 7,5 [mm]
- Weight approx.: 1,5 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 500 pieces per ammo

1) Valid, if leads are kept at ambient temperature at a distance of 10 mm from case

2)  $I_F = 5\text{ A}$ ,  $T_J = 25\text{ }^\circ\text{C}$

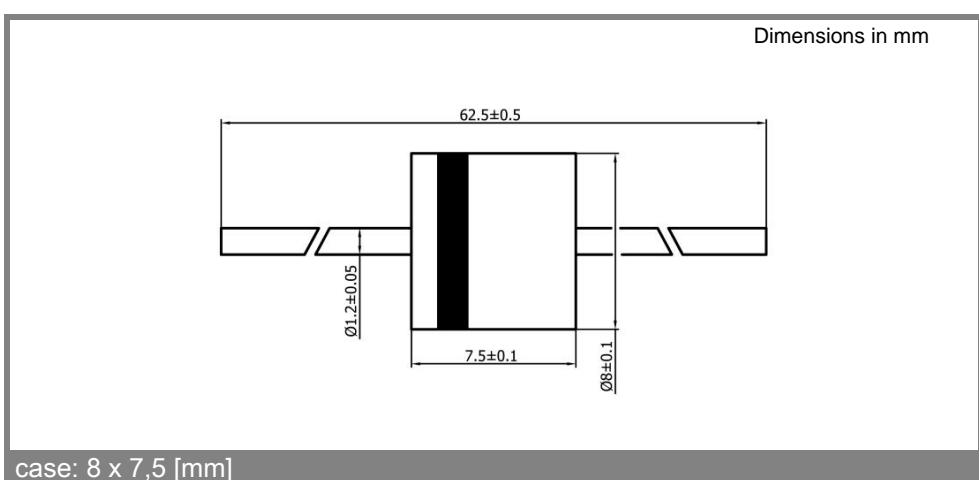
3)  $T_A = 25\text{ }^\circ\text{C}$

**Absolute Maximum Ratings**  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified

Symbol	Conditions	Values	Units
$I_{FAV}$	Max. averaged fwd. current, R-load, $T_A = 50\text{ }^\circ\text{C}$ <sup>1)</sup>	12	A
$I_{FRM}$	Repetitive peak forward current $f > 15\text{ Hz}$ <sup>1)</sup>	80	A
$I_{FSM}$	Peak forward surge current 50 Hz half sinus-wave <sup>3)</sup>	375	A
$i^2t$	Rating for fusing, $t < 10\text{ ms}$ <sup>3)</sup>	680	A <sup>2</sup> s
$R_{thA}$	Max. thermal resistance junction to ambient <sup>1)</sup>	12	K/W
$R_{thL}$	Max. thermal resistance junction to terminals <sup>4)</sup>	-	K/W
$T_j$	Operating junction temperature	-50...+150	°C
$T_s$	Storage temperature	-50...+175	°C

**Characteristics**  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified

Symbol	Conditions	Values	Units
$I_R$	Maximum leakage current, $T_j = 25\text{ }^\circ\text{C}$ ; $V_R = V_{RRM}$	<25	µA
	$T_j = °\text{C}$ ; $V_R = V_{RRM}$		
$C_J$	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
$Q_{rr}$	Reverse recovery charge ( $U_R = V$ ; $I_F = A$ ; $dI_F/dt = A/\text{ms}$ )	-	µC
$E_{RSM}$	Non repetitive peak reverse avalanche energy ( $I_R = \text{mA}$ ; $T_j = °\text{C}$ ; inductive load switched off)	-	mJ



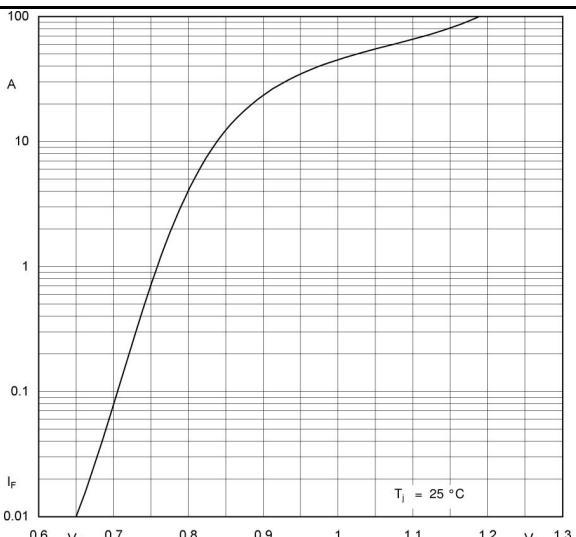


Fig. 1 Forward characteristic ( typical values ) <sup>1)</sup>

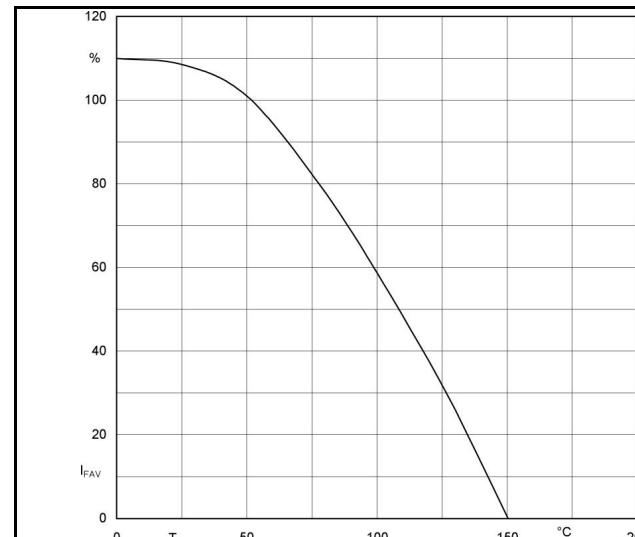


Fig. 2 Rated forward current vs. ambient temperature <sup>1)</sup>

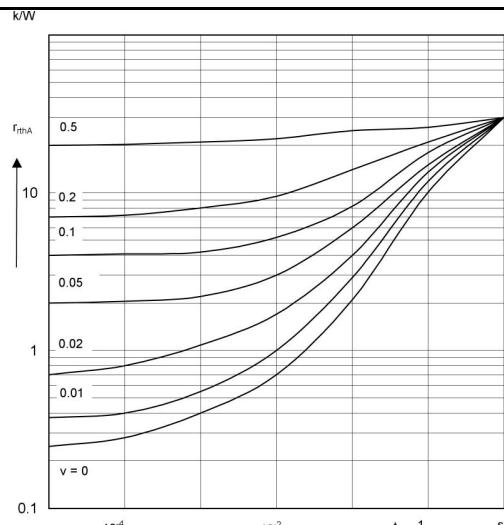


Fig. 3 Pulse thermal resistance vs. pulse duration <sup>1)</sup>